A roadmap for electronic grade 2D materials

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Citation Report

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1	The Computational Design of Two-Dimensional Materials. Journal of Chemical Education, 2019, 96, 2308-2314.	1.1	8
2	Enhancing Photoluminescence and Mobilities in WS ₂ Monolayers with Oleic Acid Ligands. Nano Letters, 2019, 19, 6299-6307.	4.5	80
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